# Rectifier - STEALTH™ II 8 A, 600 V

# FFD08S60S-F085

The FFD08S60S–F085 is stealth 2 rectifier with soft recovery characteristics ( $t_{rr}$  < 30 ns). They has half the recovery time of hyperfast rectifier and are silicon nitride passivated ion–implanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

#### **Features**

- High Speed Switching (Max.  $t_{rr} < 30$  ns @  $I_F = 8$  A)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- Pb-Free and RoHS Compliant

# **Applications**

- General Purpose
- Switching Mode Power Supply
- Boost Diode in Continuous Mode Power Factor Corrections
- Power Switching Circuits

# ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V
V <sub>R</sub>	DC Blocking Voltage	600	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 115°C	8	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave	80	Α
$T_J, T_{STG}$	Operating Junction and Storage Temperature	-65 to + 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

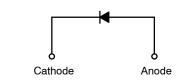
Symbol	Parameter	Ratings	Unit
$R_{ heta JC}$	Maximum Thermal Resistance, Junction to Case	3.0	°C/W

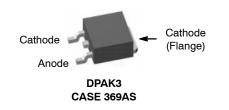
1



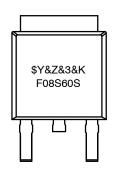
# ON Semiconductor®

#### www.onsemi.com





#### **MARKING DIAGRAM**



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code &K = Lot Code F08S60S = Specific Device Code

# **ORDERING INFORMATION**

Device	Package	Shipping		
FFD08S60-F085	DPAK3 (Pb-Free)	2500 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### FFD08S60S-F085

# **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>FM</sub> (Note 1)	I <sub>F</sub> = 8 A, I <sub>F</sub> = 8 A	T <sub>C</sub> = 25°C T <sub>C</sub> = 125°C	- -	2.1 1.6	2.6 -	V
I <sub>RM</sub> (Note 1)	V <sub>R</sub> = 600 V, V <sub>R</sub> = 600 V	T <sub>C</sub> = 25°C T <sub>C</sub> = 125°C	- -	- -	100 500	μΑ
t <sub>rr</sub>	$I_F = 1 \text{ A, di/dt} = 100 \text{ A/}\mu\text{s, V}_R = 30 \text{ V}$	T <sub>C</sub> = 25°C	-	_	25	ns
t <sub>rr</sub>	I <sub>F</sub> = 8 A, di/dt = 200 A/μs, V <sub>R</sub> = 390 V	T <sub>C</sub> = 25°C	_	19	30	ns
I <sub>rr</sub>			_	2.2	-	Α
S factor			_	0.6	_	
Q <sub>rr</sub>			_	21	_	nC
t <sub>rr</sub>	$I_F = 8 \text{ A, di/dt} = 200 \text{ A/}\mu\text{s, V}_R = 390 \text{ V}$	T <sub>C</sub> = 125°C	-	58	-	ns
I <sub>rr</sub>			_	4.3	-	Α
S factor			_	1.3	-	
Q <sub>rr</sub>				125		nC
$W_{AVL}$	Avalanche Energy (L = 40 mH)		20	_	_	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **TEST CIRCUIT AND WAVEFORMS**

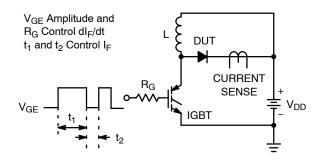


Figure 1. t<sub>rr</sub> Test Circuit

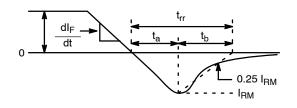


Figure 2. t<sub>rr</sub> Waveform and Definitions

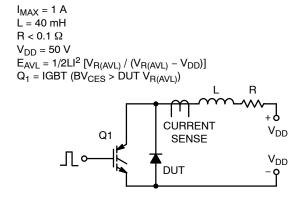


Figure 3. Avalanche Energy Test Circuit

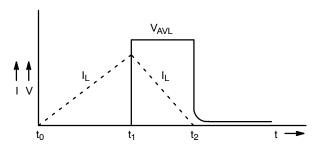


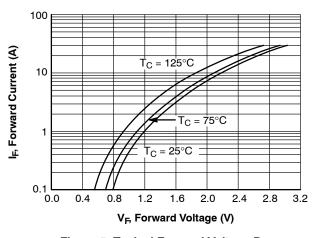
Figure 4. Avalanche Current and Voltage Waveforms

<sup>1.</sup> Pulse: Test Pulse width = 300 μs, Duty Cycle = 2%.

## FFD08S60S-F085

### **TYPICAL CHARACTERISTICS**

(T<sub>C</sub> = 25°C unless otherwise noted)



1E-4

1E-5

1E-6

T<sub>C</sub> = 125°C

1E-7

1E-7

1E-8

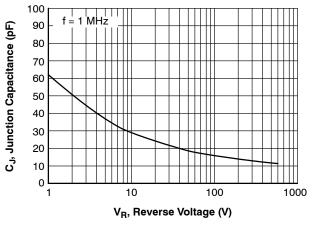
1E-9

0 100 200 300 400 500 600

V<sub>R</sub>, Reverse Voltage (V)

Figure 5. Typical Forward Voltage Drop

**Figure 6. Typical Reverse Current** 



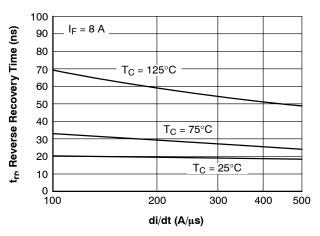
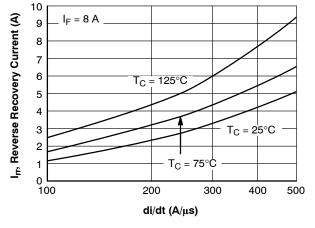


Figure 7. Typical Junction Capacitance

Figure 8. Typical Reverse Recovery Time



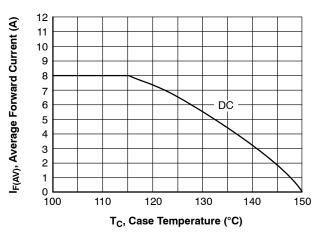
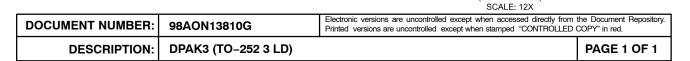


Figure 9. Typical Reverse Recovery Current

Figure 10. Forward Current Deration Curve

STEALTH is a trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.

### DPAK3 (TO-252 3 LD) CASE 369AS **ISSUE O DATE 30 SEP 2016** 6.73 6.35 5,46 5.55 MIN-6.50 MIN 6.40 Ċ 0.25 MAX PLASTIC BODY STUB MIN DIODE PRODUCTS VERSION (0.59)-1.25 MIN 0.89 ⊕ 0.25 M AM C 2.29 2.28 4.56 4.57 LAND PATTERN RECOMMENDATION NON-DIODE PRODUCTS VERSION В 2.39 SEE 2.18 4.32 MIN NOTE D 0.58 0.45 5.21 MIN 10.41 9.40 SEE DETAIL A 2 3 NON-DIODE PRODUCTS VERSION DIODE PRODUCTS VERSION ○ 0.10 B 0,51 **GAGE PLANE** NOTES: UNLESS OTHERWISE SPECIFIED 0.61 0.45 A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, (1.54)ISSUE C, VARIATION AA. B) ALL DIMENSIONS ARE IN MILLIMETERS. C) DIMENSIONING AND TOLERANCING PER 10° ASME Y14.5M-2009. D) SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED 1 78 CORNERS OR EDGE PROTRUSION.



ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

E TRIMMED CENTER LEAD IS PRESENT ONLY FOR DIODE PRODUCTS

G) LAND PATTERN RECOMENDATION IS BASED ON IPC7351A STD TO228P991X239-3N.

F) DIMENSIONS ARE EXCLUSSIVE OF BURSS,

MOLD FLASH AND TIE BAR EXTRUSIONS.

0.127 MAX

**DETAIL A** (ROTATED -90°)

**SEATING PLANE** 

1,40

(2.90)

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

#### **PUBLICATION ORDERING INFORMATION**

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

70HFR40 RL252-TP 150KR30A 1N5397 NTE5841 NTE6038 SCF5000 1N4002G 1N4005-TR JANS1N6640US 481235F
RRE02VS6SGTR 067907F MS306 70HF40 T85HFL60S02 US2JFL-TP A1N5404G-G CRS04(T5L,TEMQ) ACGRA4007-HF
ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077
85HFR60 40HFR60 70HF120 85HFR80 D126A45C SCF7500 D251N08B SCHJ22.5K SM100 SCPA2 SCH10000 SDHD5K VS12FL100S10 ACGRA4001-HF D1821SH45T PR D1251S45T NTE5990 NTE6358 NTE6162 NTE5850